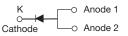
Vishay General Semiconductor

High Current Density Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.39$ V at $I_F = 4$ A



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DESIGN SUPPORT TOOLS

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PRIMARY CHARACTERISTICS				
I _{F(AV)}	8.0 A			
V _{RRM}	60 V			
I _{FSM}	140 A			
V_F at I_F = 8.0 A (T_A = 125 °C)	0.52 V			
T _J max.	175 °C			
Package	SMPC (TO-277A)			
Circuit configuration	Single			

FEATURES

- Very low profile typical height of 1.1 mm
- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 gualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V8PM6	UNIT	
Device marking code		V8M6		
Maximum repetitive peak reverse voltage	V _{RRM}	60	V	
Maximum avarage forward rectified autrent (fig. 1)	I _F ⁽¹⁾	8.0	Α	
Maximum average forward rectified current (fig. 1)	I _F ⁽²⁾	4.3		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	140	A	
Operating junction temperature range	T _J ⁽³⁾	-40 to +175	°C	
Storage temperature range	T _{STG}	-55 to +175	°C	

Notes

(1) Mounted on 30 mm x 30 mm pad areas aluminum PCB

⁽²⁾ Free air, mounted on recommended copper pad area

 $^{(3)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J <1/ R_{θ JA}

Revision: 19-Oct-2018

1

Document Number: 87428

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V8PM6

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 4.0 A	– T _A = 25 °C	V _F ⁽¹⁾	0.50	-	V
	I _F = 8.0 A			0.58	0.64	
	I _F = 4.0 A	T _A = 125 °C		0.39	-	
	I _F = 8.0 A			0.52	0.60	
Reverse current	V 60.V	T _A = 25 °C	1 (2)	-	0.6	m (
	$V_{\rm R} = 60 \text{ V}$ $T_{\rm A} = 125 \text{ °C}$	I _R ⁽²⁾	3.5	14	mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1150	-	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V8PM6	UNIT	
Tunical thormal registeres	R _{0JA} ⁽¹⁾⁽²⁾	75	°C/W	
Typical thermal resistance	R _{0JM} ⁽³⁾	4		

Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/R_{\theta JA}$ ⁽²⁾ Free air mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ - junction to ambient

⁽³⁾ Mounted on 30 mm x 30 mm aluminum PCB; thermal resistance $R_{\theta JM}$ - junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V8PM6-M3/H	0.10	Н	1500	7" diameter plastic tape and reel	
V8PM6-M3/I	0.10	I	6500	13" diameter plastic tape and reel	
V8PM6HM3/H ⁽¹⁾	0.10	н	1500	7" diameter plastic tape and reel	
V8PM6HM3/I ⁽¹⁾	0.10		6500	13" diameter plastic tape and reel	

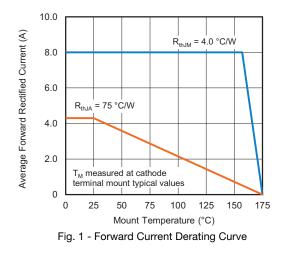
Note

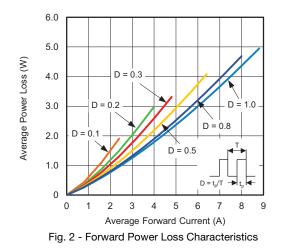
(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)





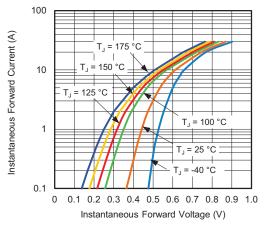


Fig. 3 - Typical Instantaneous Forward Characteristics

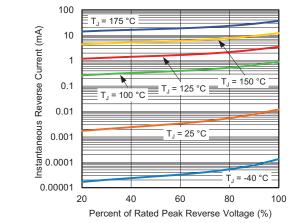
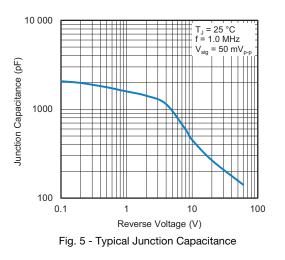


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode



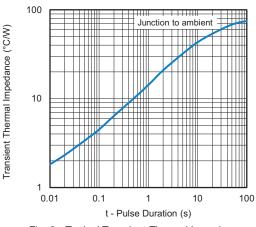


Fig. 6 - Typical Transient Thermal Impedance

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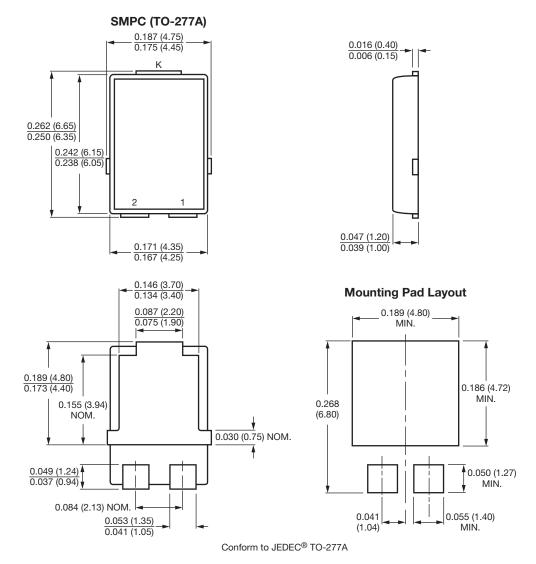
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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